NSN 5961-01-006-8000

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-006-8000 **Inclosure Material:** Metal **Overall Length:** 0.200 inches **Overall Diameter:** Between 0.450 inches and 0.500 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 4.0 breakdown voltage, emitter-to-base, collector open and 33.0 breakdown voltage, collector-to-emitter, base open **Power Rating Per Characteristic:** 70.0 watts small-signal input power, common-collector **Special Features:** Heat sink included; junction pattern arrangement: npn **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: